

BISTAR

TP7F54M
TP7F54M(H) **108 half-cell**

390 - 410W

10BB half-cut mono perc
full black



KEY FEATURES



10BB half-cut cell technology

New circuit design, lower internal current, lower Rs loss
Ga doped wafer, attenuation < 2% (1st year) / ≤ 0.55% (Linear)



Significantly lower the risk of hot spot

Special circuit design with much lower hot spot temperature



Lower LCOE

2% more power generation, lower LCOE



Excellent Anti-PID performance

2 times of industry standard Anti-PID test by TUV SUD



IP68 junction box

High waterproof level

SYSTEM & PRODUCT CERTIFICATES

- IEC 61215 / IEC 61730 / UL 61730
- ISO 9001: 2015 Quality Management System
- ISO 14001: 2015 Environment Management System
- ISO 45001: 2018 Occupational Health and Safety Management Systems



PERFORMANCE WARRANTY



Linear Performance Warranty

Standard Performance Warranty



